**Confirmation No.: 2529** 

25 October 2005

PTO/SB/21 (09-04)
Approved for use through 07/31/2006. OMB 0651-0031
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SINU SIS SISSING	Application Number	10/708,530		
TRANSMITTAL	Filing Date	10 March 2004		
FORM	First Named Inventor	Ramachandra Divakaruni		
	Art Unit	2818		
(to be used for all correspondence after initial filing)	Examiner Name	Phuc T. Dang		
Total Number of Pages in This Submission 17	Attorney Docket Number	FIS920030421US1		
	ICLOSURES (Chack a)	I that annivi		

ENCLOSURES (Check all that apply)							
V		smittal Form		Drawing(s) Licensing-related Papers			After Allowance Communication to TC  Appeal Communication to Board of Appeals and Interferences
Amendment/Reply After Final Affidavits/declaration(s) Extension of Time Request Express Abandonment Request Information Disclosure Statement  Certified Copy of Priority Document(s) Reply to Missing Parts/ Incomplete Application Reply to Missing Parts under 37 CFR 1.52 or 1.53		Petition Petition Convert to a Provisional Application Power of Attorney, Revocation Change of Correspondence Address Appeal Communication to TC (Appeal Notice, Brief, Reply Brief) Proprietary Information Status Letter		Appeal Communication to TC (Appeal Notice, Brief, Reply Brief)  Proprietary Information  Status Letter  Other Enclosure(s) (please Identify			
		SIGNA	TURE	OF APPLICANT, ATT	ORNEY, C	R AG	ENT
Firm N	lame	Graham S. Jones	II				
Signature							
Printed name Graham S. Jones, II							
Date 25 October 2005 Reg. No. 20		20,4	29				
Lharah	CERTIFICATE OF TRANSMISSION/MAILING  I hereby certify that this correspondence is being facsimile transmitted to the USPTO or deposited with the United States Postal Service with						
sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on the date shown below:							
Signat	ture	14					

This collection of information is required by 37 CFR 1.5. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.11 and1.14. This collection is estimated to 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commercial Patents P.O. Box 1450, Alexandria, VA 22313-1450. ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Graham S. Jones, II

Typed or printed name

**Confirmation No.: 2529** 

PTO/SB/17 (12-04)

Approved for use through 07/31/2006. OMB 0651-0032
U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE

Underthe Panerwork Reduction	n Act of 1995	no nersons are required to	respond to a collection of in	formation unless it displays	a valid OMB control number	
	e on 12/08/20		Complete if Known			
Fees pursuant to the Consolidated Appropriations Act, 2005 (H.R. 4818).			Application Number	10/708,530		
FEE TRANSMITTAL [			Filing Date	10 March 2004		
For	FY 20	005	First Named Invento	r Ramachandra Div	/akaruni	
Applicant claims amall a	ntitu atatua	Soc 37 CEP 1 27	Examiner Name	Examiner Name Phuc T. Dang		
Applicant claims small e	enuty status.		Art Unit	2818		
TOTAL AMOUNT OF PAYN	IENT (\$)	0	Attorney Docket No.	FIS920030421US1		
METHOD OF PAYMENT	(check all	that apply)				
Check Credit Card Money Order None Other (please identify):    Other (please identify):						
For the above-identifi	ed deposit a	ccount, the Director is h	ereby authorized to: (che	eck all that apply)		
Charge fee(s)	ndicated bel	low	Charge fee	e(s) indicated below, exc	ept for the filing fee	
under 37 CFR WARNING: Information on this	Charge any additional fee(s) or underpayments of fee(s)  Credit any overpayments  WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038.					
FEE CALCULATION						
1. BASIC FILING, SEAR	FILING F			AMINATION FEES Small Entity		
Application Type	Fee (\$)	Fee (\$) Fee	(\$) <u>Fee (\$) F</u>	ee (\$) Fee (\$)	Fees Paid (\$)	
Utility	300	150 500	250	200 100		
Design	200	100 100	50	130 65		
Plant	200	100 300	150	160 80	<del></del>	
Reissue	300	150 500	250	500 300		
Provisional	200	100 0	0	0 0	<del></del>	
2. EXCESS CLAIM FEES Fee Description Each claim over 20 or, for Reissues, each claim over 20 and more than in the original patent Each independent claim over 3 or, for Reissues, each independent claim more than in the original patent Multiple dependent claims  Small Entity Fee (\$) Fee (\$)  25  20  100  360  180						
<u>Total Claims</u> <u>E</u> 20 - 20 or HP =	xtra Claims 0			utiple Dependent Claim Fee (\$) Fee Pa		
20 - 20 or HP = 0 x = Fee (\$) Fee Paid (\$)  HP = highest number of total claims paid for, if greater than 20  Indep. Claims Extra Claims Fee (\$) Fee Paid (\$)  3 - 3 or HP = 0 x = HP = highest number of independent claims paid for, if greater than 3						
3. APPLICATION SIZE FEE  If the specification and drawings exceed 100 sheets of paper, the application size fee due is \$250 (\$125 for small entity)  for each additional 50 sheets or fraction thereof. See 35 U.S.C. 41(a)(1)(G) and 37 CFR 1.16(s).  Total Sheets  - 100 = / 50 = (round up to a whole number) x =  4. OTHER FEE(S)  Fee Paid (\$)						
Non-English Specification, \$130 fee (no small entity discount)  Other:						

SUBMITTED BY Registration No. 20,429 Telephone (845) 473-9118 Signature Date Graham S. Jones, Il 25 October 2005 Name (Print/Type)

This collection of information is required by 37 CFR 1.136. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 30 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Mail in an Envelope Addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 25 October 2005

Date Of Deposit

Graham S. Jones, II; Reg. No. 20,429

Name of Person Making Deposit

Signature

25 October 2005

Date

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Inventors:	Ramachandra Divakaruni et al.	Date:	25 October 2005	
Serial No.:	10/708,530	Art Unit:	2818	
Filing Date:	10 March 2004 Examiner: Phuc T. Dang		Phuc T. Dang	
Confirmation No.	2529 Docket No.: FIS920030421US		FIS920030421US1	
Title:	Method for Manufacturing Tungsten/Polysilicon Word Line Structure in Vertical DRAM and Device Manufactured Thereby	Attorney:	Graham S. Jones, II 42 Barnard Avenue Poughkeepsie, NY 12603-5023	

## **AMENDMENT**

The Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## Your Honor:

In response to the Office Action of 25 July 2005, please amend the above-identified application as follows:

Amendments to the Title	begin on page 2	of this paper.
Amendments to the Specification	begin on page 3	of this paper
Amendments to the Abstract	begin on page 5	of this paper
Amendments to the Claims	begin on page 6	of this paper.
Remarks/Arguments	begin on page 11	of this paper.

Serial No.: 10/718,530	Art Unit: 2818
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# **IN THE TITLE**

Please amend the title to read as follows:

- - Method for Manufacturing Tungsten/Polysilicon Word Line Structure in Vertical DRAM and Device Manufactured Thereby - -